NSN 5962-01-303-5998

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View Online at https://aerobasegroup.com/nsn/5962-01-303-5998 **Overall Length:** 1.200 inches **Overall Height:** 0.425 inches **Body Length:** 1.200 inches **Body Width:** Between 0.500 inches and 0.610 inches **Body Height:** Between 0.150 inches and 0.210 inches **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **Features Provided:** Schottky and bipolar and 3-state output and programmable and monolithic **Inclosure Material:** Ceramic **Inclosure Configuration:** Dual-in-line **Output Logic Form:** Transistor-transistor logic **Input Circuit Pattern:** 12 input **Terminal Surface Treatment:** Solder **Product Name:** Gate, array Voltage Rating And Type Per Characteristic: -0.5 volts power source and 12.0 volts power source **Memory Device Type:** Pal **Test Data Document:** 96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.). **Terminal Type And Quantity:** 24 printed circuit Shelf Life: N/a **Unit Of Measure:**

Demilitarization:

Yes - demil/mli

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